



1N4148 / 1N4448

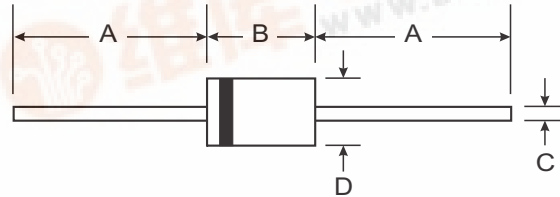
FAST SWITCHING DIODE

Features

- Fast Switching Speed
- General Purpose Rectification
- Silicon Epitaxial Planar Construction
- **Lead Free Finish, RoHS Compliant (Note 2)**

Mechanical Data

- Case: DO-35
- Case Material: Glass
- Moisture Sensitivity: Level 1 per J-STD-020C
- Leads: Solderable per MIL-STD-202, Method 208
- Terminals: Finish — Sn96.5Ag3.5. Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Marking: Type Number
- Weight: 0.13 grams (approximate)



DO-35		
Dim	Min	Max
A	25.40	—
B	—	4.00
C	—	0.60
D	—	2.00
All Dimensions in mm		

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	1N4148	1N4448	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	100		V
Peak Repetitive Reverse Voltage	V_{RRM}	75		V
Working Peak Reverse Voltage	V_{RWM}	75		V
DC Blocking Voltage	V_R	75		V
RMS Reverse Voltage	$V_{R(RMS)}$	53		V
Forward Continuous Current (Note 1)	I_{FM}	300	500	mA
Average Rectified Output Current (Note 1)	I_O	150		mA
Non-Repetitive Peak Forward Surge Current @ $t = 1.0\text{s}$ @ $t = 1.0\mu\text{s}$	I_{FSM}	1.0 2.0		A
Power Dissipation (Note 1) Derate Above 25°C	P_d	500 1.68		mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{\theta JA}$	300		$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	T_j, T_{STG}	-65 to +175		$^\circ\text{C}$

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Maximum Forward Voltage	V_{FM}	— 0.62 —	1.0 0.72 1.0	V	$I_F = 10\text{mA}$ $I_F = 5.0\text{mA}$ $I_F = 100\text{mA}$
Maximum Peak Reverse Current	I_{RM}	—	5.0 50 30 25	μA μA μA nA	$V_R = 75\text{V}$ $V_R = 70\text{V}, T_j = 150^\circ\text{C}$ $V_R = 20\text{V}, T_j = 150^\circ\text{C}$ $V_R = 20\text{V}$
Total Capacitance	C_T	—	4.0	pF	$V_R = 0, f = 1.0\text{MHz}$
Reverse Recovery Time	t_{rr}	—	4.0	ns	$I_F = 10\text{mA}$ to $I_R = 1.0\text{mA}$ $V_R = 6.0\text{V}, R_L = 100\Omega$

- Notes: 1. Valid provided that device terminals are kept at ambient temperature.
2. EC Directive 2002/95/EC (RoHS) revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied where applicable, see EU Directive Annex Notes 5 and 7.



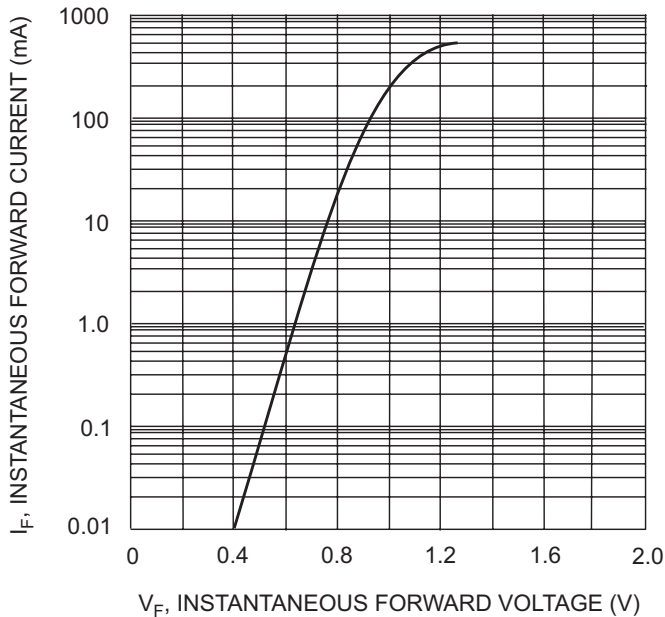


Fig. 1 Forward Characteristics

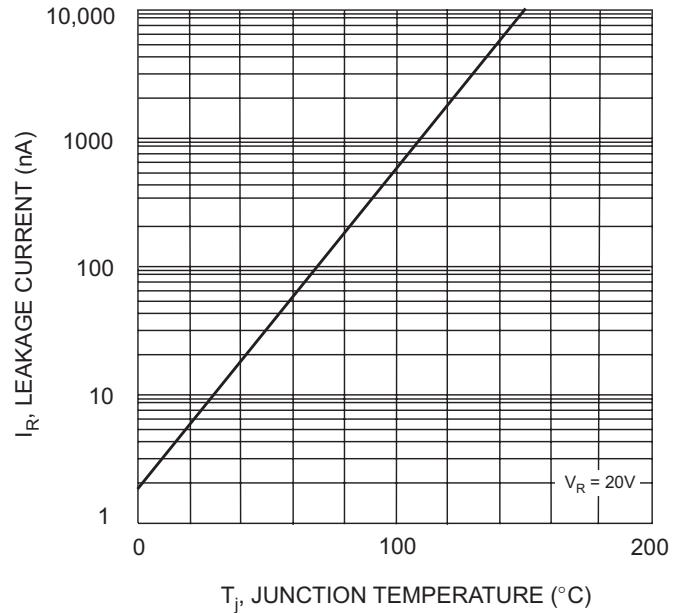


Fig. 2, Leakage Current vs Junction Temperature

Ordering Information (Note 3)

Device	Packaging	Shipping
1N4148-A	DO-35	10K/Ammo Pack
1N4148-T	DO-35	10K/Tape & Reel, 13-inch
1N4448-A	DO-35	10K/Ammo Pack
1N4448-T	DO-35	10K/Tape & Reel, 13-inch

Notes: 3. For packaging details, visit our website at <http://www.diodes.com/datasheets/ap02008.pdf>.

IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.